

Silicon NPN Power Transistors

2SC4518 2SC4518A

DESCRIPTION

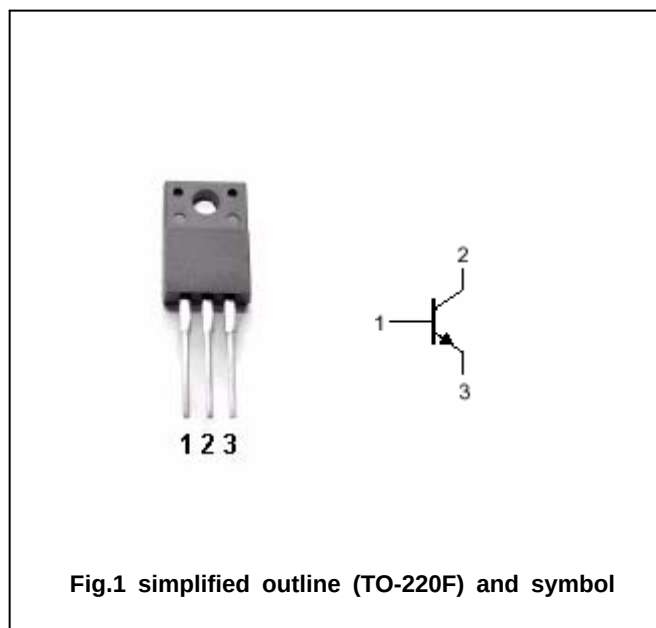
- With TO-220F package
- High voltage switching transistor

APPLICATIONS

- For switching regulator ;lighting inverter and general purpose applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter



Absolute maximum ratings (Ta=25°C)

SYMBOL	PARAMETER		CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	2SC4518	Open emitter	900	V
		2SC4518A		1000	
V_{CEO}	Collector-emitter voltage		Open base	550	V
V_{EBO}	Emitter-base voltage		Open collector	7	V
I_C	Collector current			5	A
I_{CM}	Collector current-pulse			10	A
I_B	Base current			2.5	A
P_C	Collector power dissipation		$T_C=25^{\circ}\text{C}$	35	W
T_j	Junction temperature			150	$^{\circ}\text{C}$
T_{stg}	Storage temperature			-55~150	$^{\circ}\text{C}$

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CHARACTERISTICS

T_j=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =10mA ; I _B =0	550			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =1.8A; I _B =0.36A			0.5	V
V _{BEsat}	Base-emitter saturation voltage	I _C =1.8A; I _B =0.36A			1.2	V
I _{CBO}	Collector cut-off current	V _{CB} =800V; I _E =0			100	μA
I _{EBO}	Emitter cut-off current	V _{EB} =7V; I _C =0			100	μA
h _{FE}	DC current gain	I _C =1.8A ; V _{CE} =4V	10		25	
C _{OB}	Output capacitance	I _E =0; V _{CB} =10V; f=1MHz		50		pF
f _T	Transition frequency	I _E =-0.35A ; V _{CE} =12V		6		MHz

Switching times

t _{on}	Turn-on time	I _C =1.8A; I _{B1} =0.27A I _{B2} =-0.9A V _{CC} =250V , R _L =139Ω			0.7	μs
t _s	Storage time				4.0	μs
t _f	Fall time				0.5	μs

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PACKAGE OUTLINE

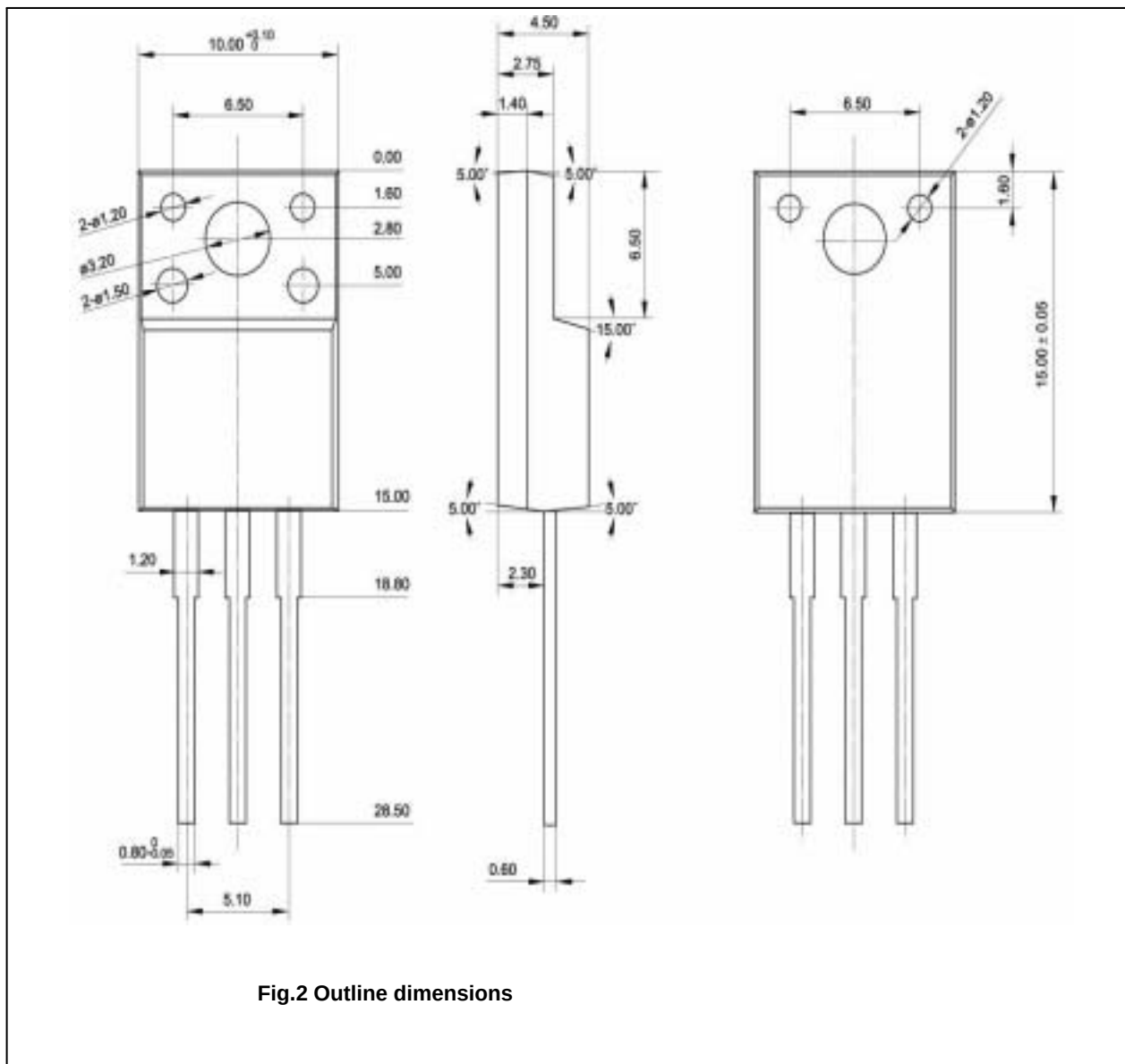


Fig.2 Outline dimensions

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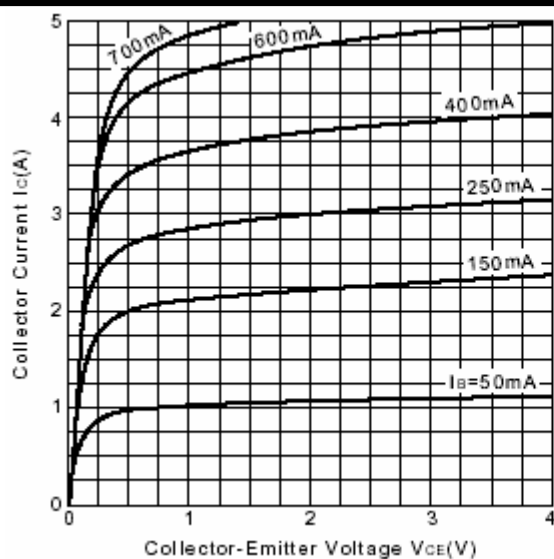


Fig.3 Static Characteristic

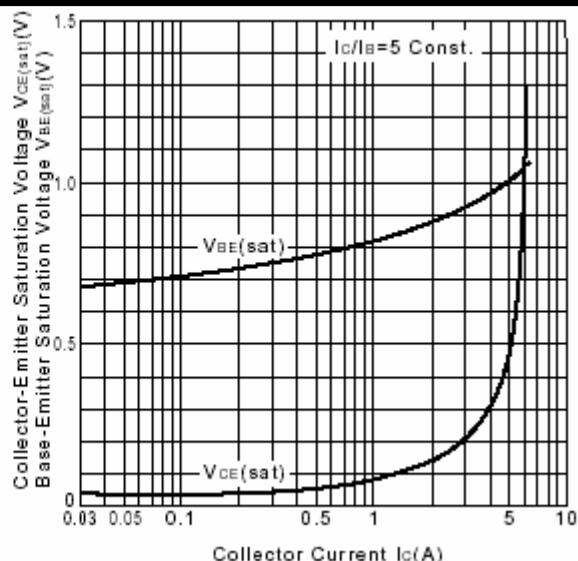
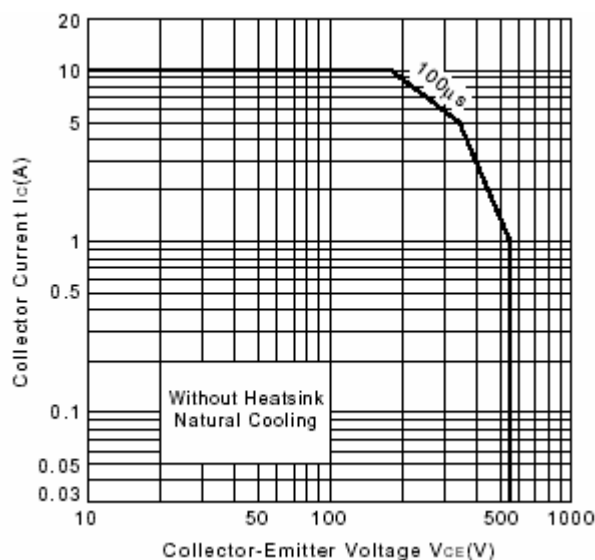
Fig.4 Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

Fig.5 Safe Operating Area

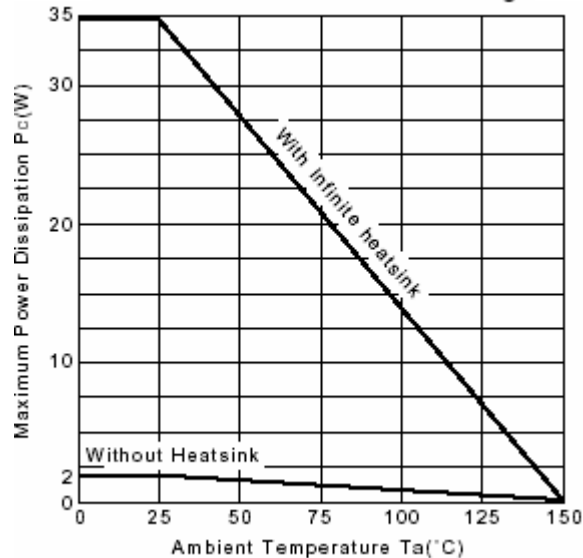
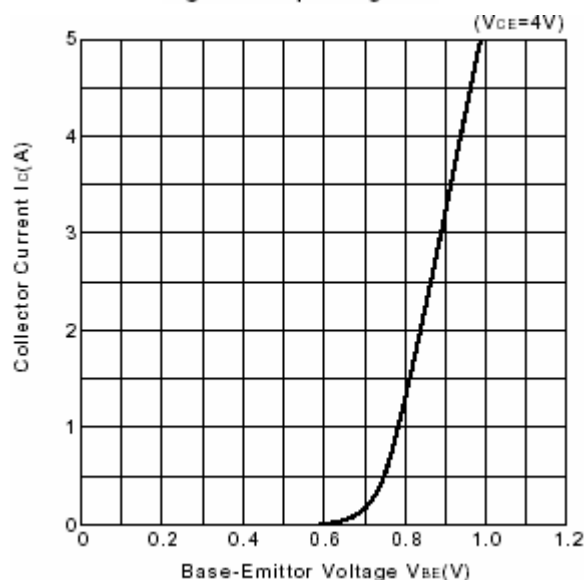
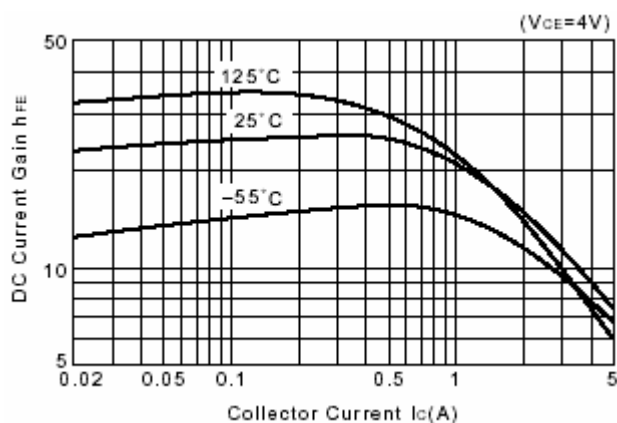
Fig.6 P_c - T_a DeratingFig.7 I_c - V_{BE} 

Fig.8 DC current Gain